MOSFET – Power, P-Channel, SOT-23 -20 V, -1 A

Features

- Ultra Low On-Resistance Provides Higher Efficiency and Extends Battery Life
 - $R_{DS(on)} = 0.180 \Omega$, $V_{GS} = -10 V$ $R_{DS(on)} = 0.280 \Omega$, $V_{GS} = -4.5 V$
- Power Management in Portable and Battery-Powered Products
- Miniature SOT-23 Surface Mount Package Saves Board Space
- Mounting Information for SOT-23 Package Provided
- NVR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- DC-DC Converters
- Computers
- Printers
- PCMCIA Cards
- Cellular and Cordless Telephones

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	-20	V
Gate-to-Source Voltage - Continuous	V _{GS}	±20	V
Drain Current - Continuous @ T_A = 25°C - Pulsed Drain Current ($t_p \le 1 \mu s$)	I _D I _{DM}	-1.0 -2.67	А
Total Power Dissipation @ T _A = 25°C	P_{D}	400	mW
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance; Junction-to-Ambient	$R_{\theta JA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, (1/8" from case for 10 s)	TL	260	°C

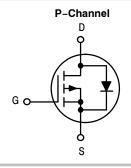
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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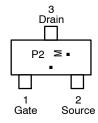
V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX	
-20 V	148 mΩ @ –10 V	–1.0 A	



MARKING DIAGRAM/ **PIN ASSIGNMENT**



SOT-23 **CASE 318** STYLE 21



P2 = Specific Device Code

= Date Code = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NTR1P02T1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NTR1P02T3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
NVR1P02T1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•		
Drain-to-Source Breakdown Voltage $(V_{GS} = 0 \text{ V}, I_D = -10 \mu\text{A})$ (Positive Temperature Coefficient)	V _{(BR)DSS}	-20	32		V mV/°C
Zero Gate Voltage Drain Current $(V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 25^{\circ}\text{C})$ $(V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 150^{\circ}\text{C})$	I _{DSS}			-1.0 -10	μΑ
Gate-Body Leakage Current ($V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$)	I _{GSS}			±100	nA
ON CHARACTERISTICS (Note 1)					
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = -250 \mu A)$ (Negative Temperature Coefficient)	V _{GS(th)}	-1.1	-1.9 -4.0	-2.3	V mV/°C
Static Drain-to-Source On-State Resistance ($V_{GS} = -10 \text{ V}$, $I_D = -1.5 \text{ A}$) ($V_{GS} = -4.5 \text{ V}$, $I_D = -0.75 \text{ A}$)	R _{DS(on)}		0.148 0.235	0.180 0.280	Ω
DYNAMIC CHARACTERISTICS					
Input Capacitance $(V_{DS} = -5 \text{ V}, V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz})$	C _{iss}		165		pF
Output Capacitance $(V_{DS} = -5 \text{ V}, V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz})$	C _{oss}		110		
Reverse Transfer Capacitance $(V_{DS} = -5 \text{ V}, V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz})$	C _{rss}		35		
SWITCHING CHARACTERISTICS (Note 2)					
Turn–On Delay Time (V_{DD} = -15 V, I_{D} = -1 A, V_{GS} = -5 V, R_{G} = 2.5 Ω)	t _{d(on)}		7.0		ns
Rise Time (V_{DD} = -15 V, I_{D} = -1 A, V_{GS} = -5 V, R_{G} = 2.5 Ω)	t _r		9.0		
Turn–Off Delay Time $(V_{DD}=-15~V,~I_{D}=-1~A,~V_{GS}=-5~V,~R_{G}=2.5~\Omega)$	^t d(off)		9.0		
Fall Time $(V_{DD} = -15 \text{ V}, I_D = -1 \text{ A}, V_{GS} = -5 \text{ V}, R_G = 2.5 \Omega)$	t _f		3.0		
Total Gate Charge $(V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V}, I_D = -0.8 \text{ A})$	Q _{tot}		2.5		nC
Gate–Source Charge $(V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V}, I_D = -0.8 \text{ A})$	Q_{gs}		0.75		
Gate-Drain Charge $(V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V}, I_D = -0.8 \text{ A})$	Q_{gd}		1.0		
BODY-DRAIN DIODE RATINGS (Note 1)		•	•		
Diode Forward On–Voltage (Note 2) ($I_S = -0.6 \text{ A}, V_{GS} = 0 \text{ V}$) ($I_S = -0.6 \text{ A}, V_{GS} = 0 \text{ V}, T_J = 150^{\circ}\text{C}$)	V _{SD}		-0.8 -0.6	-1.0	V
Reverse Recovery Time	t _{rr}		13.5		ns
$(I_S = -1 \text{ A, d}I_S/dt = 100 \text{ A/}\mu\text{s, V}_{GS} = 0 \text{ V})$	t _a		10.5		1
	t _b		3.0		1
Reverse Recovery Stored Charge $(I_S = -1 \text{ A, } dI_S/dt = 100 \text{ A/}\mu\text{s, V}_{GS} = 0 \text{ V})$	Q _{RR}		0.008		μС

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

2. Switching characteristics are independent of operating junction temperature.

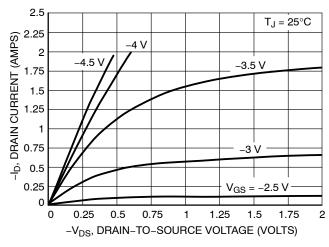


Figure 1. On-Region Characteristics

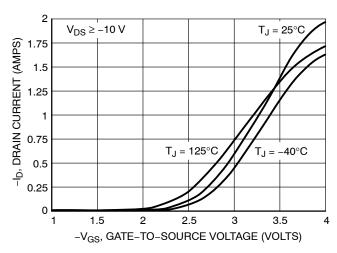


Figure 2. Transfer Characteristics

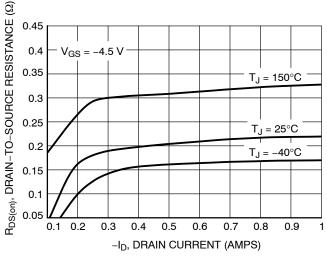


Figure 3. On-Resistance versus Drain Current and Temperature

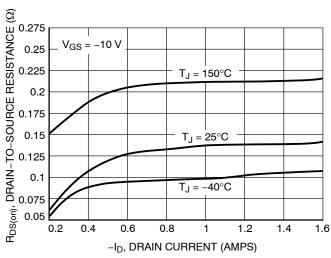


Figure 4. On-Resistance versus Drain Current and Temperature

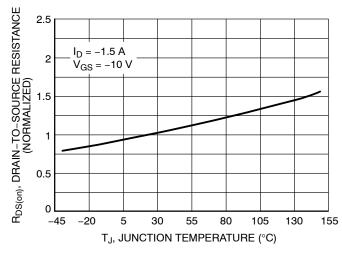


Figure 5. On–Resistance Variation with Temperature

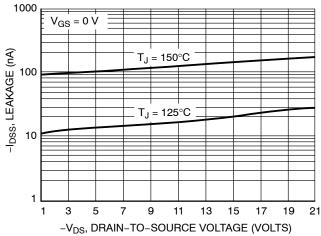


Figure 6. Drain-to-Source Leakage Current versus Voltage

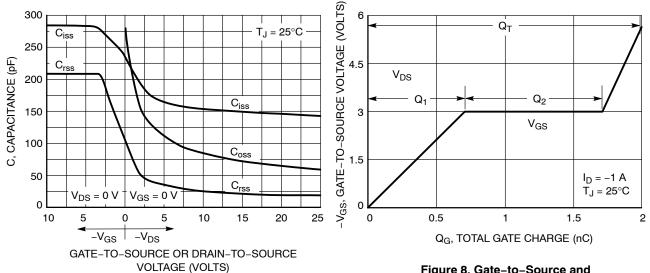


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

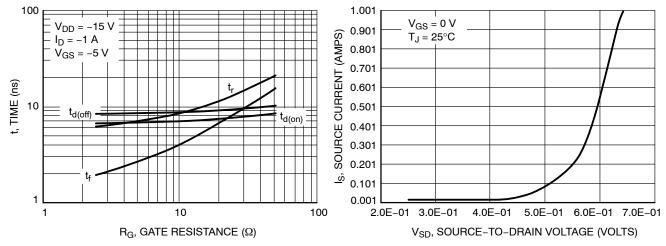


Figure 9. Resistive Switching Time Variation versus Gate Resistance

Figure 10. Diode Forward Voltage versus Current

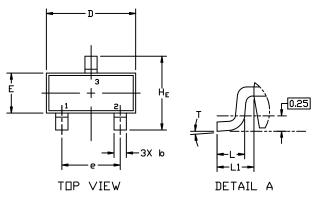




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DATE 01 MAR 2023









NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		INCHES			
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Ε	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10°	0*		10°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

■ = Pb-Free Package



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

STYLES ON PAGE 2

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



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DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	1	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE		PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE		2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE		3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	N PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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